





# J230, J231 N-Channel JFET

Technical

Support

#### Features

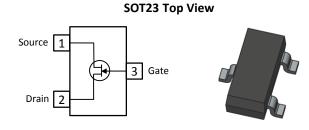
- InterFET <u>N0016SH Geometry</u>
- Low Noise: 5 nV/VHz Typical
- Low Ciss: 4pF Typical
- RoHS Compliant
- SMT, TH, and Bare Die Package options.

### **Applications**

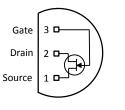
- Audio Amplifiers
- Small Signal Amplifier
- Ultrahigh Impedance Pre-Amplifier

# Description

The -40V InterFET J230 and J231 are targeted for sensitive amplifier stages for mid-frequencies designs. Gate leakages are typically less than 10pA at room temperatures.



#### **TO-92 Bottom View**





#### **Product Summary**

	Parameters	J230 Min	J231 Min	Unit
BV <sub>GSS</sub>	Gate to Source Breakdown Voltage	-40	-25	V
I <sub>DSS</sub>	Drain to Source Saturation Current	0.7	2	mA
V <sub>GS(off)</sub>	Gate to Source Cutoff Voltage	-0.5	-1.5	V
G <sub>FS</sub>	Forward Transconductance	1000	1500	μS

#### Ordering Information Custom Part and Binning Options Available

Part Number	Description	Case	Packaging
J230; J231	Through-Hole	TO-92	Bulk
SMPJ230; SMPJ231	Surface Mount	SOT23	Bulk
	7" Tape and Reel: Max 3,000 Pieces		Minimum 1,000 Pieces
SMPJ230TR; SMPJ231TR	13" Tape and Reel: Max 9,000 Pieces	SOT23	Tape and Reel
J230COT; J231COT	Chip Orientated Tray (COT Waffle Pack)	COT	400/Waffle Pack
J230CFT; J231CFT	Chip Face-up Tray (CFT Waffle Pack)	CFT	400/Waffle Pack



**Disclaimer:** It is the Buyers responsibility for designing, validating and testing the end application under all field use cases and extreme use conditions. Guaranteeing the application meets required standards, regulatory compliance, and all safety and security requirements is the responsibility of the Buyer. These resources are subject to change without notice.







# **Electrical Characteristics**

#### Maximum Ratings (@ T<sub>A</sub> = 25°C, Unless otherwise specified)

	Parameters	Value	Unit
VRGS	Reverse Gate Source and Gate Drain Voltage	-40	V
$I_{FG}$	Continuous Forward Gate Current	50	mA
PD	Continuous Device Power Dissipation	360	mW
Р	Power Derating	3.27	mW/°C
Τı	Operating Junction Temperature	-55 to 125	°C
T <sub>STG</sub>	Storage Temperature	-65 to 200	°C

## **Static Characteristics** (@ TA = 25°C, Unless otherwise specified)

			J230		J231				
	Parameters	Conditions	Min	Тур	Max	Min	Тур	Max	Unit
V(BR)GSS	Gate to Source Breakdown Voltage	$V_{DS} = 0V$ , $I_G = -1\mu A$	-40			-40			V
Igss	Gate to Source Reverse Current	$V_{GS} = -30V, V_{DS} = 0V$			-250			-250	рА
V <sub>GS(OFF)</sub>	Gate to Source Cutoff Voltage	$V_{DS} = 20V, I_D = 1\mu A$	-0.5		-3	-1.5		-5	V
I <sub>DSS</sub>	Drain to Source Saturation Current	$V_{GS} = 0V, V_{DS} = 20V$ (Pulsed)	0.7		3	2		6	mA
lg	Gate Operating Current	V <sub>DS</sub> = 10V, I <sub>D</sub> = 500uA		-2			-2		pА

## Dynamic Characteristics (@ TA = 25°C, Unless otherwise specified)

			J230 J231						
	Parameters	Conditions	Min	Тур	Max	Min	Тур	Max	Unit
GFS	Forward Transconductance	$V_{DS} = 20V, V_{GS} = 0V, f = 1kHz$	1000		3500	1500		4000	μS
Gos	Output Conductance	$V_{DS} = 20V, V_{GS} = 0V, f = 1kHz$		1.5			3		μS
Ciss	Input Capacitance	$V_{DS} = 20V, V_{GS} = 0V, f = 1MHz$		4			4		pF
C <sub>rss</sub>	Reverse Transfer Capacitance	$V_{DS} = 20V, V_{GS} = 0V, f = 1MHz$		1			1		pF
en	Noise Voltage	$V_{DS} = 10V, V_{GS} = 0V, f = 10Hz$ $V_{DS} = 10V, V_{GS} = 0V, f = 1kHz$		8 2	30		8 2	30	nV/√Hz



Technical

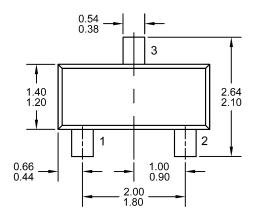
Support

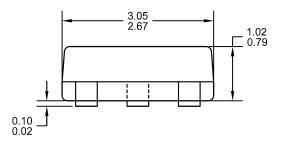
Order

Now

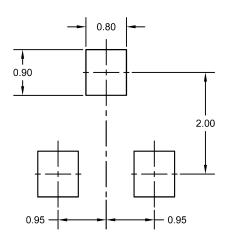
# SOT23 (TO-236AB) Mechanical and Layout Data

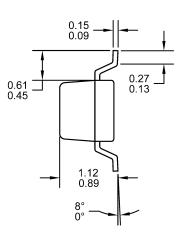
#### **Package Outline Data**





## Suggested Pad Layout





- 1. All linear dimensions are in millimeters.
- 2. Package weight approximately 0.12 grams
- 3. Molded plastic case UL 94V-0 rated
- For Tape and Reel specifications refer to InterFET CTC-021 Tape and Reel Specification, Document number: IF39002
- 5. Bulk product is shipped in standard ESD shipping material
- 6. Refer to JEDEC standards for additional information.

- 1. All linear dimensions are in millimeters.
- 2. The suggested land pattern dimensions have been provided for reference only. A more robust pattern may be desired for wave soldering.

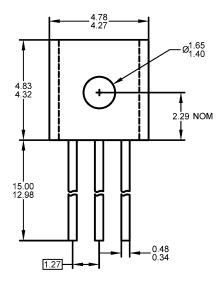


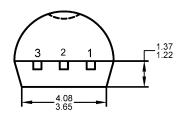


Support

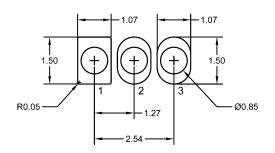
# **TO-92 Mechanical and Layout Data**

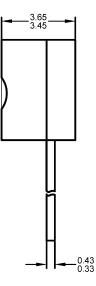
# **Package Outline Data**





# Suggested Through-Hole Layout





- All linear dimensions are in millimeters. 1.
- 2. Package weight approximately 0.19 grams
- 3. Molded plastic case UL 94V-0 rated
- 4. Bulk product is shipped in standard ESD shipping material
- 5. Refer to JEDEC standards for additional information.

- 1. All linear dimensions are in millimeters.
- 2. The suggested land pattern dimensions have been provided as a straight lead reference only. A more robust pattern may be desired for wave soldering and/or bent lead configurations.

# **Mouser Electronics**

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

InterFET:

<u>J230</u> <u>SMPJ230</u> <u>SMPJ231</u> <u>J231</u>